

10A Lead Type Low Barrier Diode

■ Features

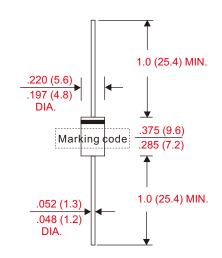
- Axial lead type devices for through hole design.
- Low forward voltage drop.
- Excellent high temperature stability.
- · Fast switching capability.
- Suffix "G" indicates Halogen-free part, ex.CSR1045G-A.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

■ Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- · Case: Molded plastic, DO-201AD / DO-27
- Lead : Axial leads, solderable per MIL-STD-202, Method 208 guranteed
- Polarity: Color band denotes cathode end
- Weight: Approximated 1.10 gram

■ Outline

DO-27(DO-201AD)



Dimensions in inches and (millimeters)

■ Maximum ratings and electrical characteristics

Rating at 25° C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Parameter | Conditions | Symbol | CSR1045-A | | | UNIT |
|-----------------------------------|--|---------------------|------------|------|------------|------|
| Marking code | | | CSR1045 | | | |
| Peak repetitive reverse voltage | | V _{RRM} | | | | |
| Working peak reverse voltage | | V _{RWM} | 45 | | | V |
| DC blocking voltage | | V _{RM} | | | | |
| RMS reverse voltage | | V _{R(RMS)} | 32 | | | V |
| Forward rectified current | | Io | 10 | | | Α |
| Forward surge current | 8.3ms single half sine-wave superimposed on rate load (JEDEC method) | I _{FSM} | 180 | | | А |
| Thermal resistance | Junction to ambient | R _{eJA} | 54 | | | °C/W |
| | Junction to case | R _{eJL} | 18 | | | °C/W |
| Operating and Storage temperature | | T_J, T_{STG} | -65 ~ +150 | | | °C |
| Parameter | Conditions | Symbol | MIN. | TYP. | MAX. | UNIT |
| Reverse breakdown voltage | I _P = 0.5mA | V _{(BR)R} | 45 | | 1417 (7 4. | V |
| Forward voltage drop | $I_F = 8A, T_J = 25^{\circ}C$ | V _F | | | 510 | mV |
| | I _F = 10A, T _J = 25°C | | | | 550 | |
| | I _F = 10A, T _J = 125°C | | | | 530 | |
| Reverse current | $V_R = V_{RRM} T_J = 25^{\circ}C$ | I _R | | | 0.45 | mA |
| | $V_R = V_{RRM} T_J = 100^{\circ}C$ | | | | 18 | |
| | $V_R = V_{RRM} T_J = 125^{\circ}C$ | | | | 100 | |

Document ID : DS-11KC7 Revised Date : 2013/09/05

Revision : C1



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■ Rating and characteristic curves

Fig. 2 - Instantaneous Forward Characteristics

100 $T_{\lambda}=150^{\circ}\text{C}$ $T_{\lambda}=100^{\circ}\text{C}$ $T_{\lambda}=100^{\circ}\text{C}$ $T_{\lambda}=75^{\circ}\text{C}$ Instantaneous Forward Voltage, V_F (Volts)

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Document ID : DS-11KC7 Revised Date : 2013/09/05

Revision : C1